

View Online at <https://aerobasegroup.com/nsn/5980-01-169-1807>

General Description:

Gallium arsenide diode infraed source optically coupled to silicon npn phototransistor; 6 lead plastic dip; storage temp m55 degrees to p150 degrees celcius

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A23900